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**Amendments to the Claims:**

A listing of the entire set of pending claims is submitted herewith per 37 CFR 1.121. This listing of claims will replace all prior versions, and listings, of claims in the application:

**Listing of Claims:**

1-7 (Canceled)

8. (Currently amended) A semiconductor device ~~characterized by~~, comprising:  
a source electrode formed on a substrate~~[[,]]~~;  
a source bus formed on said source electrode~~[[,]]~~; and  
a drain electrode that is formed on said substrate and ~~comprises~~  
includes a first electrode and a second electrode formed on said first electrode,  
~~and further characterized in that wherein~~ an edge portion of said source  
electrode protrudes toward said drain electrode relative to an edge portion of said  
source bus and an edge portion of said first electrode of said drain electrode  
protrudes toward said source electrode relative to said second electrode.

9. (Currently amended) ~~[[A]] The semiconductor device as claimed in of claim 8,~~  
~~characterized in that wherein~~ each edge portion of said source electrode, said source  
bus, said first electrode and said second electrode is formed into a surface ~~which~~  
that is perpendicular to said substrate.

10. (Currently amended) ~~[[A]] The semiconductor device as claimed in of claim 8,~~  
~~characterized in that wherein~~ each edge portion of said source electrode, said source  
bus, said first electrode and said second electrode, is formed into a surface which  
that is inclined relative to said substrate.